12A, 23V, 500kHz, ACOT™ Synchronous Buck Converter with VTT LDO for Memory Power Supply

General Description

The RT7241A provides a complete power supply for DDR3/DDR3L/LPDDR3/DDR4 memory systems. It integrates an Advanced Constant On-Time (ACOT™) mode synchronous Buck converter with a 1.5A sink/source tracking linear regulator.

The PWM converter provides low quiescent supply current, high efficiency, excellent transient response, and high DC output accuracy needed for stepping down high-voltage batteries to generate low-voltage chipset RAM supplies in notebook computers. The ACOT™ control scheme handles wide input/output voltage ratios with ease and provides a very fast response to load transients with no external compensators.

The 1.5A sink/source VTT LDO maintains fast transient response only requiring 10μF ceramic output capacitance. The RT7241A supports all of the sleep state controls placing VTT at high-Z in S3 and discharging VDDQ and VTT in S4/S5.

The RT7241A provides complete protection features including OCP, OVP, UVP, and thermal shutdown. The RT7241A is available in the UQFN-18L 3x4 package.

Applications

- DDR3/DDR3L/LPDDR3/DDR4 Memory Power Supplies
- Notebook computers

Features

- DDR3/DDR3L/LPDDR3/DDR4 Complete Solution
- PWM Converter (VDDQ)
  - 100μA Low Quiescent Supply Current at S3 Mode
  - ACOT™ Mode Performs Fast Transient Response
  - Support MLCC Output Capacitors
  - Integrated Low On-Resistance MOSFETs
    - 17mΩ of High-Side MOSFET
    - 4.5mΩ of Low-Side MOSFET
  - Adjustable from 0.6V to 1.5V Output Range for 1.5V (DDR3), 1.35V (DDR3L), 1.2V (LPDDR3) and 1.2V (DDR4)
  - 4.5V to 23V Battery Input Range
  - 500kHz Switching Frequency
  - Resistor Adjustable Valley Current Limit
  - Over-/Under-Voltage Protection
  - Internal Voltage Ramp Soft-Start
  - Power Good Indicator
- 1.5A LDO (VTT)
  - Capable to Sink and Source up to 1.5A
  - LDO Input Available to Optimize Power Losses
  - Require Only 10μF Ceramic Output Capacitor
  - Integrated Divider Tracks 1/2 VDDQ for VTT
  - Accuracy ±20mV for VTT
  - Support High-Z in S3 and Soft-Off in S4/S5
- Tracking Mode Discharge Control
- Thermal Capable Flip-chip (FC) Package for 12A VDDQ Converter and 1.5A VTT LDO
- RoHS Compliant and Halogen Free

Simplified Application Circuit

Marking Information

00=YM DNN
00= : Product Code
YMDNN : Date Code
## Functional Pin Description

<table>
<thead>
<tr>
<th>Pin No.</th>
<th>Pin Name</th>
<th>Pin Function</th>
</tr>
</thead>
<tbody>
<tr>
<td>1</td>
<td>S3</td>
<td>VTT LDO enable control input. Do not leave this pin floating.</td>
</tr>
<tr>
<td>2</td>
<td>BOOT</td>
<td>Bootstrap supply for high-side gate driver. A capacitor is needed to drive the power switch's gate above the supply voltage. It is connected between the PHASE and BOOT pins to form a floating supply across the power switch driver.</td>
</tr>
<tr>
<td>3, 4</td>
<td>PHASE</td>
<td>Switch node. External inductor connection for VDDQ.</td>
</tr>
<tr>
<td>5</td>
<td>VDDQ</td>
<td>Reference input for the VTT LDO. An internal discharging circuit is connected to this pin.</td>
</tr>
<tr>
<td>6</td>
<td>VLDOIN</td>
<td>Power supply for the VTT LDO.</td>
</tr>
<tr>
<td>7</td>
<td>VTT</td>
<td>Power output for the VTT LDO.</td>
</tr>
<tr>
<td>8</td>
<td>VTTGND</td>
<td>Power ground for the VTT LDO.</td>
</tr>
<tr>
<td>9</td>
<td>VTTSNS</td>
<td>Voltage sense input for the VTT LDO. Connect to the terminal of the VTT LDO output capacitor.</td>
</tr>
<tr>
<td>10, 11</td>
<td>PGND</td>
<td>Power ground for VDDQ.</td>
</tr>
<tr>
<td>12</td>
<td>VIN</td>
<td>Supply input for VDDQ.</td>
</tr>
<tr>
<td>13</td>
<td>PGOOD</td>
<td>Open-drain power good indicator output.</td>
</tr>
<tr>
<td>14</td>
<td>VDD</td>
<td>Analog supply input.</td>
</tr>
<tr>
<td>15</td>
<td>GND</td>
<td>Analog ground.</td>
</tr>
<tr>
<td>16</td>
<td>FB</td>
<td>Feedback voltage input. Connect to a resistive voltage divider from VDDQ to GND to adjust the output of PWM converter.</td>
</tr>
<tr>
<td>17</td>
<td>CS</td>
<td>Current limit threshold setting input. Connect to GND through the setting resistor.</td>
</tr>
<tr>
<td>18</td>
<td>S5</td>
<td>PWM converter enable control input. Do not leave this pin floating.</td>
</tr>
</tbody>
</table>

## Pin Configuration

![Pin Configuration Diagram](image)

Note:

- Richtek products are:
  - RoHS compliant and compatible with the current requirements of IPC/JEDEC J-STD-020.
  - Suitable for use in SnPb or Pb-free soldering processes.

## Ordering Information

**RT7241A**

- **Package Type**: QUFN-18L 3x4 (FC) (U-Type)
- **Lead Plating System**: G: Green (Halogen Free and Pb Free)

Note:

Richtek products are:

- RoHS compliant and compatible with the current requirements of IPC/JEDEC J-STD-020.
- Suitable for use in SnPb or Pb-free soldering processes.
Functional Block Diagram

Buck Converter

VTT LDO
Absolute Maximum Ratings (Note 1)

- **VIN to PGND**: −0.3V to 27V
- **SW to PGND**: −0.3V to 27.3V
- **BOOT to PGND**: −0.6V to 33.3V
- **S3, VDDQ, VLDOIN, VTT, VTTSNS, PGOOD, VDD, FB, CS, S5 to GND**: −0.3V to 6V
- **PGND to GND**: −0.3V to 0.3V
- **PGND to VTTGND**: −0.3V to 0.3V
- **GND to VTTGND**: −0.3V to 0.3V
- **Power Dissipation, PD @ TA = 25°C**: 3.03W
- **Package Thermal Resistance (Note 2)**: 33°C/W
- **Lead Temperature (Soldering, 10 sec.)**: 260°C
- **Junction Temperature**: 150°C
- **Storage Temperature Range**: −65°C to 150°C
- **ESD Susceptibility (Note 3)**: 2kV

Recommended Operating Conditions (Note 3)

- **Supply Input Voltage, VIN**: 4.5V to 23V
- **Junction Temperature Range**: −40°C to 125°C
- **Ambient Temperature Range**: −40°C to 85°C

Electrical Characteristics

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Symbol</th>
<th>Test Conditions</th>
<th>Min</th>
<th>Typ</th>
<th>Max</th>
<th>Unit</th>
</tr>
</thead>
<tbody>
<tr>
<td><strong>Supply Current</strong></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Quiescent Supply Current</td>
<td>FB forced above the regulation point, VSS = 2V, VS3 = 0V</td>
<td>80</td>
<td>100</td>
<td>130</td>
<td>µA</td>
<td></td>
</tr>
<tr>
<td>IVLDOIN BIAS Current</td>
<td>VSS = VS3 = 2V, VTT = no load</td>
<td>--</td>
<td>1</td>
<td>--</td>
<td>µA</td>
<td></td>
</tr>
<tr>
<td>IVLDOIN Standby Current</td>
<td>VSS = 2V, VS3 = 0V, VTT = no load</td>
<td>--</td>
<td>0.1</td>
<td>10</td>
<td>µA</td>
<td></td>
</tr>
<tr>
<td>Shutdown Current</td>
<td>VSS = VS3 = 0V</td>
<td>--</td>
<td>2.5</td>
<td>10</td>
<td>µA</td>
<td></td>
</tr>
<tr>
<td><strong>PWM Converter</strong></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>VDDQ Voltage Range</td>
<td></td>
<td></td>
<td>0.6</td>
<td>--</td>
<td>1.5</td>
<td>V</td>
</tr>
<tr>
<td>VDDQ Input Resistance</td>
<td></td>
<td></td>
<td>--</td>
<td>100</td>
<td>--</td>
<td>kΩ</td>
</tr>
<tr>
<td>VDDQ Shutdown Discharge Resistance</td>
<td>VSS = 0V</td>
<td>--</td>
<td>15</td>
<td>--</td>
<td>Ω</td>
<td></td>
</tr>
<tr>
<td><strong>Switch On-Resistance</strong></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Switch On-Resistance</td>
<td>RDS(ON)H</td>
<td>VBOOT − VPHASE = 5V</td>
<td>--</td>
<td>17</td>
<td>--</td>
<td>mΩ</td>
</tr>
<tr>
<td></td>
<td>RDS(ON)L</td>
<td></td>
<td>--</td>
<td>4.5</td>
<td>--</td>
<td>mΩ</td>
</tr>
<tr>
<td><strong>Current Limit</strong></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Current Limit</td>
<td>ILIM</td>
<td>Valley current of low-side switch, RCS = 165kΩ</td>
<td>--</td>
<td>16</td>
<td>--</td>
<td>A</td>
</tr>
</tbody>
</table>
## Switching Frequency and Min. Off Timer

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Symbol</th>
<th>Test Conditions</th>
<th>Min</th>
<th>Typ</th>
<th>Max</th>
<th>Unit</th>
</tr>
</thead>
<tbody>
<tr>
<td>Switching Frequency</td>
<td>$f_{SW}$</td>
<td></td>
<td>425</td>
<td>500</td>
<td>575</td>
<td>kHz</td>
</tr>
<tr>
<td>Minimum On Time</td>
<td>$t_{ON}$</td>
<td></td>
<td>--</td>
<td>60</td>
<td>--</td>
<td>ns</td>
</tr>
<tr>
<td>Minimum Off Time</td>
<td>$t_{OFF}$</td>
<td></td>
<td>--</td>
<td>200</td>
<td>--</td>
<td>ns</td>
</tr>
</tbody>
</table>

## Output Under-Voltage and Over-Voltage Protection

| OVP Trip Threshold               | $V_{OVP}$ | Measured at FB, with respect to reference voltage | 112  | 117  | 122  | %    |
| OVP Propagation Delay            | $T_{OVPDLY}$ | FB force above OVP threshold | --   | 5    | --   | μs   |
| UVP Trip Threshold               | $V_{UVP}$ | Measured at FB, with respect to reference voltage | 60   | 70   | 80   | %    |
| UVP Propagation Delay            | $T_{UVPDLY}$ | FB force below UVP threshold | --   | 2    | --   | μs   |

## Reference and Soft-Start

| FB Reference Voltage             | $V_{REF}$ |                                  | 0.594 | 0.6  | 0.606 | V    |
| FB Input Bias Current            | $V_{FB}$ = 0.6V |                             | --1   | 0.1  | 1     | μA   |
| Soft-Start Time                  | $t_{SS}$ | From S5 high to 90% of $V_{REF}$ | 0.5   | 1    | 1.5   | ms   |

## Enable and UVLO

| S3, S5 Input Voltage             | Logic-High |                                  | 0.8   | --   | --    | V    |
|                                  | Logic-Low  |                                  | --    | --   | 0.4   | V    |
| VDD Input UVLO Threshold         |            | Wake up                          | 3.9   | 4.2  | 4.5   | V    |
| VDD Input UVLO Hysteresis        |            | Shutdown                         | --    | 0.2  | --    | V    |

## Power Good

| Trip Threshold (Raising)         | Measured at FB, with respect to reference, no load | 87   | 91  | 95   | %    |
| Trip Threshold (Hysteresis)      |                                              | --   | 3   | --   | %    |
| Fault Propagation Delay          | Falling edge, FB forced below PGOOD trip threshold | --   | 2.5 | --   | μs   |
| Output Low Voltage               | $I_{SINK} = 1mA$ |                                | --   | --  | 0.4   | V    |
| Leakage Current                  | $I_{LEAK}$ | High state, forced to 5V | --   | --  | 1     | μA   |

## Thermal Shutdown

| Thermal Shutdown                 | $T_{SD}$ |                                | --   | 165 | --    | °C   |
| Thermal Shutdown Hysteresis      | $\Delta T_{SD}$ |                             | --   | 25  | --    | °C   |

## VTT LDO

| VTT Output Tolerance            | $V_{VTTTOL}$ | $V_{DDQ} = V_{LDOIN} = 1.2V / 1.35V / 1.5V / 1.8V, | $|I_{VTT}| = 0A$ | --20 | --   | 20   | mV   |
|                                  |            | $V_{DDQ} = V_{LDOIN} = 1.2V / 1.35V / 1.5V / 1.8V, | $|I_{VTT}| = 1A$ | --30 | --   | 30   |
|                                  |            | $V_{DDQ} = V_{LDOIN} = 1.2V / 1.35V, | $|I_{VTT}| = 1.2A$ | --40 | --   | 40   |
|                                  |            | $V_{DDQ} = V_{LDOIN} = 1.5V / 1.8V, | $|I_{VTT}| = 1.5A$ | --40 | --   | 40   |
Note 1. Stresses beyond those listed "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions may affect device reliability.

Note 2. $\theta_{JA}$ is measured under natural convection (still air) at $T_A = 25^\circ C$ with the component mounted on a four-layer Richtek Evaluation Board.

Note 3. Devices are ESD sensitive. Handling precaution is recommended.

Note 4. The device is not guaranteed to function outside its operating conditions.

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<th>Typ</th>
<th>Max</th>
<th>Unit</th>
</tr>
</thead>
<tbody>
<tr>
<td>VTT Source Current Limit</td>
<td>$I_{VTTOCLSRC}$</td>
<td>VTT = 0V</td>
<td>1.6</td>
<td>2.6</td>
<td>3.6</td>
<td>A</td>
</tr>
<tr>
<td>VTT Sink Current Limit</td>
<td>$I_{VTTOCLSNK}$</td>
<td>VTT = VDDQ</td>
<td>1.6</td>
<td>2.6</td>
<td>3.6</td>
<td>A</td>
</tr>
<tr>
<td>VTT Leakage Current</td>
<td>$I_{VTTLK}$</td>
<td>S5 = 5V, S3 = 0V, VTT = $\left(\frac{V_{DDQ}}{2}\right)$</td>
<td>$-10$</td>
<td>--</td>
<td>10</td>
<td>$\mu A$</td>
</tr>
<tr>
<td>VTTSNS Leakage Current</td>
<td>$I_{VTTSNSLK}$</td>
<td>$I_{SINK} = 1mA$</td>
<td>$-1$</td>
<td>--</td>
<td>1</td>
<td>$\mu A$</td>
</tr>
<tr>
<td>VTT Discharge Resistance</td>
<td>$R_{DSCHRG}$</td>
<td>S5 = S3 = 0V</td>
<td>--</td>
<td>6</td>
<td>--</td>
<td>$\Omega$</td>
</tr>
</tbody>
</table>
Typical Application Circuit

Figure 1. Typical Application Circuit for $V_{OUT} = 1.35V$

Figure 2. Typical Application Circuit for $V_{OUT} = 1.2V$
Typical Operating Characteristics

Performance waveforms are tested on the evaluation board of the Typical Application Circuit, \( V_{IN} = 12V, V_{OUT} = 1.35V, L = 0.56\mu H, T_J = 25^\circ C \), unless otherwise noted.

- **Efficiency vs. Load Current**
- **Switching Frequency vs. Load Current**
- **Quiescent Current vs. VDD Input Voltage**
- **Shutdown Current vs. VDD Input Voltage**
- **VTT Output Voltage vs. Load Current**

---

**Efficiency vs. Load Current**

- \( V_{IN} = 7.4V \)
- \( V_{IN} = 12V \)
- \( V_{IN} = 19V \)

**Switching Frequency vs. Load Current**

- \( V_{DDQ} = 1.35V, V_{DD} = 5V, f_{SW} = 500kHz, L = 0.56\mu H, DCR = 1.8m\Omega \)

**Quiescent Current vs. VDD Input Voltage**

- \( V_{IN} = 12V, S5 = 5V, S3 = GND, No Switching \)

**Shutdown Current vs. VDD Input Voltage**

- \( V_{IN} = 12V, S5 = 5V, S3 = GND \)

**VTT Output Voltage vs. Load Current**

- \( V_{IN} = 12V, V_{DDQ} = 1.35V, V_{DD} = 5V \)
VDDQ Output Voltage vs. Load Current

VDDQ Power On by S5

VDDQ Power On by VDD

VDDQ Output Voltage vs. Load Current

VDDQ Power On by S5

VDDQ Power On by VDD

VIN = 12V, VDDQ = 1.35V, VDD = 5V

VIN = 12V, No Load, VDD Hot Plug

VIN = 12V, ILOAD = 12A

VIN = 12V, No Load, VDD Hot Plug

VIN = 12V, ILOAD = 12A, VDD Hot Plug

VIN = 12V, VDDQ = 1.2V, VDD = 5V
VDDQ Power Off by S5

- $V_{DDQ}$ (400mV/Div)
- S5 (5V/Div)
- PGOOD (5V/Div)
- $I_L$ (1A/Div)

$V_{IN} = 12V$, No Load

Time (2ms/Div)

VDDQ Power Off by S5

- $V_{DDQ}$ (400mV/Div)
- S5 (5V/Div)
- PGOOD (5V/Div)
- $I_L$ (10A/Div)

$V_{IN} = 12V$, $I_{LOAD} = 12A$

Time (10\mu s/Div)

VDDQ Power Off by VDD

- $V_{DDQ}$ (400mV/Div)
- VDD (5V/Div)
- PGOOD (5V/Div)
- $I_L$ (1A/Div)

$V_{IN} = 12V$, No Load

Time (10ms/Div)

VDDQ Power Off by VDD

- $V_{DDQ}$ (400mV/Div)
- VDD (5V/Div)
- PGOOD (5V/Div)
- $I_L$ (1A/Div)

$V_{IN} = 12V$, $I_{LOAD} = 12A$

Time (10\mu s/Div)

VTT Power On by S3

- $V_{DDQ}$ (400mV/Div)
- VTT (400mV/Div)
- S3 (5V/Div)
- $I_L$ (2A/Div)

$V_{IN} = 12V$, No Load

Time (10\mu s/Div)

VTT Power Off by S3

- $V_{DDQ}$ (400mV/Div)
- VTT (400mV/Div)
- S3 (5V/Div)
- $I_L$ (2A/Div)

$V_{IN} = 12V$, No Load

Time (20ms/Div)
Application Information

The RT7241A is high-performance 500kHz 12A step-down regulators with internal power switches and synchronous rectifiers. It features an Advanced Constant On-Time (ACOT™) control architecture that provides stable operation for ceramic output capacitors without complicated external compensation, among other benefits. The input voltage range is from 4.5V to 23V. The output voltage is adjustable from 0.6V to 1.5V.

The proprietary ACOT™ control scheme improves conventional constant on-time architectures, achieving nearly constant switching frequency over line, load, and output voltage ranges. Since there is no internal clock, response to transients is nearly instantaneous and inductor current can ramp quickly to maintain output regulation without large bulk output capacitance.

The 1.5A sink/source VTT LDO maintains fast transient response, only requiring 10μF of ceramic output capacitance. The RT7241A supports all of the sleep state controls, placing VTT at high-Z in S3 and discharging VDDQ, VTT and VTTREF (soft-off) in S4/S5.

ACOT™ Control Architecture

Making the on-time proportional to VOUT and inversely proportional to VIN is not sufficient to achieve good constant-frequency behavior for several reasons. First, voltage drops across the MOSFET switches and inductor cause the effective input voltage to be less than the measured input voltage and the effective output voltage to be greater than the measured output voltage as sensing input and output voltage from LX pin. When the load change, the switch voltage drops change causing a switching frequency variation with load current. Also, at light loads if the inductor current goes negative, the switch dead-time between the synchronous rectifier turn-off and the high-side switch turn-on allows the switching node to rise to the input voltage. This increases the effective on-time and causes the switching frequency to drop noticeably.

One way to reduce these effects is to measure the actual switching frequency and compare it to the desired range. This has the added benefit eliminating the need to sense the actual output voltage, potentially saving one pin connection. ACOT™ uses this method, measuring the actual switching frequency and modifying the on-time with a feedback loop to keep the average switching frequency in the desired range.

In order to achieve good stability with low-ESR ceramic capacitors, ACOT™ uses a virtual inductor current ramp generated inside the IC. This internal ramp signal replaces the ESR ramp normally provided by the output capacitor’s ESR. The ramp signal and other internal compensations are optimized for low-ESR ceramic output capacitors.

ACOT™ One-shot Operation

The RT7241A control algorithm is simple to understand. The feedback voltage, with the virtual inductor current ramp added, is compared to the reference voltage. When the combined signal is less than the reference, the on-time one-shot is triggered, as long as the minimum off-time one-shot is clear and the measured inductor current (through the synchronous rectifier) is below the current limit. The on-time one-shot turns on the high-side switch and the inductor current ramps up linearly. After the on-time, the high-side switch is turned off and the synchronous rectifier is turned on and the inductor current ramps down linearly. At the same time, the minimum off-time one-shot is triggered to prevent another immediate on-time during the noisy switching time and allow the feedback voltage and current sense signals to settle. The minimum off-time is kept short (200ns typical) so that rapidly-repeated on-times can raise the inductor current quickly when needed.

Diode Emulation Mode

In diode emulation mode, the RT7241A automatically reduces switching frequency at light load conditions to maintain high efficiency. This reduction of frequency is achieved smoothly. As the output current decreases from heavy load condition, the inductor current is also reduced, and eventually comes to the point that its current valley touches zero, which is the boundary between continuous conduction and discontinuous conduction modes. To emulate the behavior of diodes, the low-side MOSFET allows only partial negative current to flow when the inductor free wheeling current becomes negative. As the load current is further decreased, it takes longer and longer
time to discharge the output capacitor to the level that
requires the next “ON” cycle. In reverse, when the output
current increases from light load to heavy load, the
switching frequency increases to the preset value as the
inductor current reaches the continuous conduction. The
transition load point to the light load operation is shown in
Figure 3. and can be calculated as follows:

\[ I_{LOAD} = \frac{I_{PEAK}}{2} \]

\[ \text{Slpoe} = \frac{(V_{IN} - V_{OUT})}{L} \]

\[ I_{ON} = \frac{(V_{IN} - V_{OUT})}{2L} \]

where \( I_{ON} \) is the on-time.

The switching waveforms may appear noisy and
asynchronous when light load causes diode emulation
operation. This is normal and results in high efficiency.
Trade offs in DEM noise vs. light load efficiency is made
by varying the inductor value. Generally, low inductor values
produce a broader efficiency vs. load curve, while higher
values result in higher full load efficiency (assuming that
the coil resistance remains fixed) and less output voltage
ripple. Penalties for using higher inductor values include
larger physical size and degraded load transient response
(especially at low input voltage levels).

During discontinuous switching, the on-time is immediately
increased to add “hysteresis” to discourage the IC from
switching back to continuous switching unless the load
increases substantially. The IC returns to continuous
switching as soon as an on-time is generated before the
inductor current reaches zero. The on-time is reduced back
to the length needed for 500kHz switching and encouraging
the circuit to remain in continuous conduction, preventing
repetitive mode transitions between continuous switching
and discontinuous switching.

**VTT Linear Regulator**

The RT7241A integrates a high performance low dropout
linear regulator that is capable of sourcing and sinking
currents up to 1.5A. This VTT linear regulator employs
ultimate fast response feedback loop so that small ceramic
 capacitors are enough for keeping track of VDDQ/2 within
40mV at all conditions, including fast load transient. To
achieve tight regulation with minimum effect of wiring
resistance, a remote sensing terminal, VTTSNS, should
be connected to the positive node of the VTT output
capacitor(s) as a separate trace from the VTT pin. For
stable operation, total capacitance of the VTT output
terminal can be equal to or greater than 10μF.

**Current Limit Setting for VDDQ (CS)**

The RT7241A current limit is adjustable by CS pin and it
is a cycle-by-cycle “valley” type, measuring the inductor
current through the synchronous rectifier during the off-
time while the inductor current ramps down. The current
is determined by measuring the voltage between source
and drain of the synchronous rectifier, adding temperature
compensation for greater accuracy. If the current exceeds
the current limit, the on-time one-shot is inhibited until
the inductor current ramps down below the current limit.
Thus, only when the inductor current is well below the
current limit, another on-time is permitted. If the output
current exceeds the available inductor current (controlled
by the current limit mechanism), the output voltage will
drop. If it drops below the output under-voltage protection
level (see next section) the IC will stop switching to avoid
excessive heat.

The RT7241A also includes a negative current limit to
protect the IC against sinking excessive current and
possibly damaging the IC. If the voltage across the
synchronous rectifier indicates the negative current is too
high, the synchronous rectifier turns off until after the next
high side on-time.

The RT7241A provides adjustable OCP setting via change
the RCS to decide the current limit. The current limit can
be derived by the following equation:

\[ I_{LIMIT} = \frac{2.64 \times 10^5}{R_{CS}} \]

The default setting of \( R_{CS} \) is 165kΩ, which means current
limit is 16A. The maximum current limit should be lower
than 20A.
Output Over-voltage Protection and Under-voltage Protection for VDDQ

The RT7241A includes output over-voltage protection (OVP). If the output voltage rises above the regulation level, the high-side switch naturally remains off and the synchronous rectifier will periodically turn on until the inductor current reaches the negative current limit or under-voltage protection is triggered. If the output voltage exceeds the OVP trip threshold for longer than 5μs (typical), the IC’s OVP is triggered. The RT7241A also includes output under-voltage protection (UVP). If the output voltage drops below the UVP trip threshold for longer than 2μs (typical) the IC’s UVP is triggered. The RT7241A uses latch-off mode OVP and UVP. When the protection function is triggered, the IC will shut down. The IC stops switching and is latched off. To restart operation, toggle S5 or power the IC off by VDD and then on again.

Current Protection for VTT

The LDO has an internally fixed constant over current limit of 2.6A while operating at normal condition.

VDD Under Voltage Lockout (UVLO)

In addition to the enable function, the RT7241A features an UVLO function that monitors the VDD voltage. To prevent operation without fully-enhanced internal MOSFET switches, this function inhibits switching when VDD voltage drops below the UVLO-falling threshold. The IC resumes switching when VDD voltage exceeds the UVLO-rising threshold.

Over Temperature Protection

The RT7241A includes an over temperature protection (OTP) circuitry to prevent overheating due to excessive power dissipation. The OTP will shut down switching operation when the junction temperature exceeds 165°C. Once the junction temperature cools down by approximately 25°C the IC will resume normal operation with a complete soft-start. For continuous operation, provide adequate cooling so that the junction temperature does not exceed 165°C.

Output Management by S3, S5 Control

In DDR2/DDR3 memory applications, it is important to always keep VDDQ higher than VTT/VTTREF, even during start-up and shutdown. The RT7241A provides this management by simply connecting both S3 and S5 terminals to the sleep-mode signals such as SLP_S3 and SLP_S5 in notebook PC system. All VDDQ and VTT are turned on at S0 state (S3 = S5 = high). In S3 state (S3 = low, S5 = high), VDDQ is kept on while VTT is turned off and left at high impedance (high-Z) state. The VTT output is floated and does not sink or source current in this state. In S4/S5 states (S3 = S5 = low), all of the two outputs are disabled and discharged to ground. The code of each state represents the following: S0 = full ON, S3 = suspend to RAM (STR), S4 = suspend to disk (STD), S5 = soft OFF. (See Table 1)

<table>
<thead>
<tr>
<th>STATE</th>
<th>S3</th>
<th>S5</th>
<th>VDDQ</th>
<th>VTT</th>
</tr>
</thead>
<tbody>
<tr>
<td>S0</td>
<td>Hi</td>
<td>Hi</td>
<td>On</td>
<td>On</td>
</tr>
<tr>
<td>S3</td>
<td>Lo</td>
<td>Hi</td>
<td>On</td>
<td>Off (Hi-Z)</td>
</tr>
<tr>
<td>S4/S5</td>
<td>Lo</td>
<td>Lo</td>
<td>Off (Discharge)</td>
<td>Off (Discharge)</td>
</tr>
</tbody>
</table>

VDDQ and VTT Tracking Discharge Mode

The RT7241A discharges VDDQ and VTT outputs when S5 is low or in the S4/S5 state. In tracking discharge mode, the RT7241A discharges outputs through the internal switch and VTT output tracks half of the VDDQ voltage during this discharge. Note that if VLDOIN is supplied by external voltage source, an input decoupling capacitor about 10μF is needed at the input.

The VTT LDO can handle up to 1.5A for both source/sink, and discharge with high-Z in S3.

Soft-Start

The RT7241A provides an internal soft-start function to prevent large inrush current and output voltage overshoot when the converter starts up. The soft-start (SS) automatically begins once the chip is enabled. During soft-start, it clamps the ramping of internal reference voltage which is compared with FB signal. The typical soft-start duration is 1ms.
Power Good Output (PGOOD)
The power good output is an open drain output that requires a pull-up resistor. When the output voltage is 20% (typical) below its set voltage, PGOOD will be pulled low. It is held low until the output voltage returns to 93% of its set voltage once more. During soft-start, PGOOD is actively held low and only allowed to be pulled high after soft-start is over and the output reaches 93% of its set voltage. There is a 2.5μs delay built into PGOOD circuitry to prevent false transition.

External Bootstrap Capacitor (CBOOT)
Connect a 0.1μF low ESR ceramic capacitor between BOOT pin and LX pin. This bootstrap capacitor provides the gate driver supply voltage for the high side N-channel MOSFET switch.

The internal power MOSFET switch gate driver is optimized to turn the switch on fast enough for low power loss and good efficiency, but also slow enough to reduce EMI. Switch turn-on is when most EMI occurs since VSW rises rapidly. During switch turn-off, SW is discharged relatively slowly by the inductor current during the dead-time between high-side and low-side switch on-times. In some cases it is desirable to reduce EMI further, at the expense of some additional power dissipation. The switch turn-on can be slowed by placing a small (<10Ω) resistance between BOOT and the external bootstrap capacitor. This will slow the high-side switch turn-on and VSW’s rise.

Setting the Output Voltage
The output voltage of RT7241A is adjustable and with valley control. There is an easy way to determine the output voltage only by two resistors, R1 and R2. As the feedback circuit shown in Figure 4, the relation of VOUT and VREF can be derived as VOUT = (1+R1/R2) x VREF readily. Generally, the stability is a serious issue for converter. In order to achieve better performance on stability and transient, a feed-forward capacitor, CFF, is added to increase the noise margin and transient response of loop control. However, there is a tradeoff of adding a feed-forward capacitor. An additional dc offset will be generated on output voltage due to the amplified feedback ripple by feed-forward compensator. This is not always the case that every CFF makes the same value of dc offset, it is based on different pole and zero placement generated by R1, R2 and CFF. For simplicity, a symbol named Vdc,offset is supposed to be the value of dc offset. This value may influence the performance (e.g. regulation or peak value of VOUT) of converter slightly, the suggested CFF is to select a pair of pole and zero to provide the maximum phase lead at switching frequency.

\[ V_{OUT,\text{valley}} = \left(1 + \frac{R1}{R2}\right) \times V_{REF} + V_{dc,\text{offset}} \]

VOUT, vallely is the valley of output voltage, and Vdc,offset is used for describing the additional dc offset on VOUT, the value is related to the output voltage ripple and CFF.

Figure 4. The Equivalent Circuit of Feedback Loop

Inductor Selection
Selecting an inductor involves specifying its inductance and also its required peak current. The exact inductor value is generally flexible and is ultimately chosen to obtain the best mix of cost, physical size, and circuit efficiency. Lower inductor values benefit from reduced size and cost and they can improve the circuit’s transient response, but they increase the inductor ripple current and output voltage ripple and reduce the efficiency due to the resulting higher peak currents. Conversely, higher inductor values increase efficiency, but the inductor will either be physically larger or have higher resistance since more turns of wire are required and transient response will be slower since more time is required to change current (up or down) in the inductor. A good compromise between size, efficiency, and transient response is to use a ripple current (ΔIL) about 20-50% of the desired full output load current. Calculate the approximate inductor value by selecting the input and output voltages, the switching frequency (fSW), the maximum output current (IOUT(MAX)) and estimating a ΔIL as some percentage of that current.

\[ L = \frac{V_{OUT} \times (V_{IN} - V_{OUT})}{V_{IN} \times f_{SW} \times \Delta I_L} \]
Once an inductor value is chosen, the ripple current \( \Delta I_L \) is calculated to determine the required peak inductor current.

\[
\Delta I_L = \frac{V_{OUT} \times (V_{IN} - V_{OUT})}{V_{IN} \times f_{SW} \times L}
\]

and \( I_{L(PEAK)} = I_{OUT(MAX)} + \frac{\Delta I_L}{2} \)

To guarantee the required output current, the inductor needs a saturation current rating and a thermal rating that exceeds \( I_{L(PEAK)} \). These are minimum requirements. To maintain control of inductor current in overload and short-circuit conditions, some applications may desire current ratings up to the current limit value. However, the IC’s output under-voltage shutdown feature make this unnecessary for most applications.

For best efficiency, choose an inductor with a low DC resistance that meets the cost and size requirements. For low inductor core losses some type of ferrite core is usually best and a shielded core type, although possibly larger or more expensive, will probably give fewer EMI and other noise problems.

**Input Capacitor Selection**

High quality ceramic input decoupling capacitor, such as X5R or X7R, with values greater than 20\( \mu F \) are recommended for the input capacitor. The X5R and X7R ceramic capacitors are usually selected for power regulator capacitors because the dielectric material has less capacitance variation and more temperature stability. Voltage rating and current rating are the key parameters when selecting an input capacitor. Generally, selecting an input capacitor with voltage rating 1.5times greater than the maximum input voltage is a conservatively safe design. The input capacitor is used to supply the input RMS current, which can be approximately calculated using the following equation:

\[
I_{RMS} = \frac{V_{OUT}}{V_{IN}} \times \sqrt{\left(1 - \frac{V_{OUT}}{V_{IN}}\right) \times \frac{I_{OUT}}{2} + \frac{\Delta I_L^2}{12}}
\]

The next step is to select a proper capacitor for RMS current rating. One good design uses more than one capacitor with low Equivalent Series Resistance (ESR) in parallel to form a capacitor bank. The input capacitance value determines the input ripple voltage of the regulator. The input voltage ripple can be approximately calculated using the following equation:

\[
\Delta V_{IN} = \frac{I_{OUT} \times V_{IN}}{C_{IN} \times f_{SW} \times V_{OUT}} \times \left(1 - \frac{V_{OUT}}{V_{IN}}\right)
\]

The typical operating circuit is recommended to use two 10\( \mu F \) and low ESR ceramic capacitors on the input.

**Output Capacitor Selection**

The RT7241A is optimized for ceramic output capacitors and best performance will be obtained using them. The total output capacitance value is usually determined by the desired output voltage ripple level and transient response requirements for sag (undershoot on positive load steps) and soar (overshoot on negative load steps).

Output ripple at the switching frequency is caused by the inductor current ripple and its effect on the output capacitor's ESR and stored charge. These two ripple components are called ESR ripple and capacitive ripple. Since ceramic capacitors have extremely low ESR and relatively little capacitance, both components are similar in amplitude and both should be considered if ripple is critical.

\[
V_{RIPPLE} = V_{RIPPLE(ESR)} + V_{RIPPLE(C)}
\]

\[
V_{RIPPLE(ESR)} = \Delta I_L \times R_{ESR}
\]

\[
V_{RIPPLE(C)} = \frac{\Delta I_L}{8 \times C_{OUT} \times f_{SW}}
\]

In addition to voltage ripple at the switching frequency, the output capacitor and its ESR also affect the voltage sag (undershoot) and soar (overshoot) when the load steps up and down abruptly. The ACOT transient response is very quick and output transients are usually small. However, the combination of small ceramic output capacitors (with little capacitance), low output voltages (with little stored charge in the output capacitors), and low duty cycle applications (which require high inductance to get reasonable ripple currents with high input voltages) increases the size of voltage variations in response to very quick load changes. Typically, load changes occur slowly with respect to the IC's 500kHz switching frequency. But some modern digital loads can exhibit nearly instantaneous load changes and the following section shows how to calculate the worst-case voltage swings in response to very fast load steps.

The amplitude of the ESR step up or down is a function of the load step and the ESR of the output capacitor:
ESR \_STEP = \Delta \text{OUT} \times \text{RESR}

The amplitude of the capacitive sag is a function of the load step, the output capacitor value, the inductor value, the input-to-output voltage differential, and the maximum duty cycle. The maximum duty cycle during a fast transient is a function of the on-time and the minimum off-time since the ACOT™ control scheme will ramp the current using on-times spaced apart with minimum off-times, which is as fast as allowed. Calculate the approximate on-time (neglecting parasitics) and maximum duty cycle for a given input and output voltage as:

\[
\text{t}_{\text{ON}} = \frac{\text{V}_{\text{OUT}}}{\text{V}_{\text{IN}} \times f_{\text{SW}}} \quad \text{and} \quad \text{D}_{\text{MAX}} = \frac{\text{t}_{\text{ON}}}{\text{t}_{\text{ON}} + \text{t}_{\text{OFF(MIN)}}}
\]

The actual on-time will be slightly longer as the IC compensates for voltage drops in the circuit, but we can neglect both of these since the on-time increase compensates for the voltage losses. Calculate the output voltage sag as:

\[
\text{V}_{\text{SAG}} = \frac{\text{L} \times (\Delta \text{OUT})^2}{2 \times \text{C}_{\text{OUT}} \times (\text{V}_{\text{IN(MIN)}} \times \text{D}_{\text{MAX}} - \text{V}_{\text{OUT}})}
\]

The amplitude of the capacitive soar is a function of the load step, the output capacitor value, the inductor value and the output voltage:

\[
\text{V}_{\text{SOAR}} = \frac{\text{L} \times (\Delta \text{OUT})^2}{2 \times \text{C}_{\text{OUT}} \times \text{V}_{\text{OUT}}}
\]

Most applications never experience instantaneous full load steps and the RT7241A’s high switching frequency and fast transient response can easily control voltage regulation at all times. Therefore, sag and soar are seldom an issue except in very low-voltage CPU core or DDR memory supply applications, particularly for devices with high clock frequencies and quick changes into and out of sleep modes. In such applications, simply increasing the amount of ceramic output capacitor (sag and soar are directly proportional to capacitance) or adding extra bulk capacitance can easily eliminate any excessive voltage transients.

In any application with large quick transients, it should calculate soar and sag to make sure that over-voltage protection and under-voltage protection will not be triggered.

**Thermal Considerations**

The junction temperature should never exceed the absolute maximum junction temperature \( T_{J(MAX)} \), listed under Absolute Maximum Ratings, to avoid permanent damage to the device. The maximum allowable power dissipation depends on the thermal resistance of the IC package, the PCB layout, the rate of surrounding airflow, and the difference between the junction and ambient temperatures. The maximum power dissipation can be calculated using the following formula:

\[
P_{D(MAX)} = \frac{(T_{J(MAX)} - T_{A})}{\theta_{JA}}
\]

where \( T_{J(MAX)} \) is the maximum junction temperature, \( T_{A} \) is the ambient temperature, and \( \theta_{JA} \) is the junction-to-ambient thermal resistance.

For continuous operation, the maximum operating junction temperature indicated under Recommended Operating Conditions is 125°C. The junction-to-ambient thermal resistance, \( \theta_{JA} \), is highly package dependent. For a UQFN-18L 3x4 (FC) package, the thermal resistance, \( \theta_{JA} \), is 33°C/W on a four-layer Richtek evaluation board. The maximum power dissipation at \( T_{A} = 25°C \) can be calculated as below:

\[
P_{D(MAX)} = \frac{(125°C - 25°C)}{(33°C/W)} = 3.03W \text{ for a UQFN-18L 3x4 (FC) package.}
\]

The maximum power dissipation depends on the operating ambient temperature for the fixed \( T_{J(MAX)} \) and the thermal resistance, \( \theta_{JA} \). The derating curves in Figure 5 allows the designer to see the effect of rising ambient temperature on the maximum power dissipation.

![Figure 5. Derating Curve of Maximum Power Dissipation](image-url)
Layout Considerations

Layout is very important in high frequency switching converter design. The PCB can radiate excessive noise and contribute to converter instability with improper layout. Certain points must be considered before starting a layout using the RT7241A.

- Make the traces of the main current paths as short and wide as possible. Put the input capacitor as close as possible to the device pins (VIN and GND).
- Keep current limit setting network as close as possible to the IC. Routing of the network should avoid coupling to high voltage switching node.
- Phase node encounters high frequency voltage swings so it should be kept in a small area. Keep sensitive components away from the phase node to prevent stray as possible.
- VLDOIN should be connected to VDDQ output with short and wide trace. If different power source is used for VLDOIN, an input bypass capacitor should be placed as close as possible to the pin with short and wide trace.
- The output capacitor for VTT should be placed close to the pin with short and wide connection in order to avoid additional ESR and/or ESL of the trace.
- It is strongly recommended to connect VTTSNS to the positive node of VTT output capacitor(s) as a separate trace from the high current power line to avoid additional ESR and/or ESL. If it is needed to sense the voltage of the point of the load, it is recommended to attach the output capacitor(s) at that point. It is also recommended to minimize any additional ESR and/or ESL of ground trace between the GND pin and the output capacitor(s).
- The GND pin should be connected to a strong ground plane for heat sinking and noise protection.
- Avoid using vias in the power path connections that have switched currents (from CIN to GND and CIN to VIN) and the switching node (Phase).
- An example of PCB layout guide is shown in Figure 6 for reference.

![Figure 6. PCB Layout Guide](image-url)
<table>
<thead>
<tr>
<th>Symbol</th>
<th>Dimensions In Millimeters</th>
<th>Dimensions In Inches</th>
</tr>
</thead>
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<td>Max.</td>
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**U-Type 18L QFN 3x4 (FC) Package**